

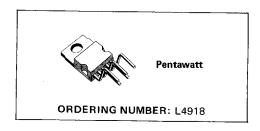
VOLTAGE REGULATOR PLUS FILTER

- FIXED OUTPUT VOLTAGE 8.5V
- 250mA OUTPUT CURRENT
- HIGH RIPPLE REJECTION
- HIGH LOAD REGULATION
- HIGH LINE REGULATION
- SHORT CIRCUIT PROTECTION
- THERMAL SHUT DOWN WITH HYSTER-ESIS
- DUMP PROTECTION

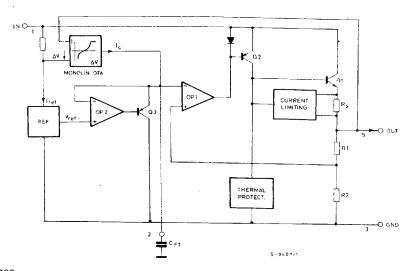
The L4918 combines both a filter and a voltage regulator in order to provide a high ripple rejection over a wider input voltage range.

A supervisor low-pass loop of the element prevents the output transistor from saturation at low input voltages.

The non linear behaviour of this control circuitry allows a fast setting of the filter.



BLOCK DIAGRAM



June 1988

7929237 0051143 221

1/5

129

ABSOLUTE MAXIMUM RATINGS

· · ·	Peak input voltage (300ms)	40	V
V 5 V -	DC voltage	28	٧
lo .	Output current	internally limited	
P _{tot}	Power dissipation	internally limited	^ -
T _{stq} , T _i	Storage and junction temperature	-40 to 150	°C

CONNECTION DIAGRAM

(Top view)

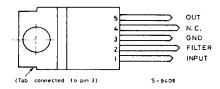
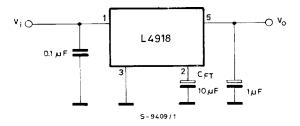


Fig. 1 - Application and test circuit



THERMAL DATA

R _{th j-case}	Thermal resistance junction-case				max	4	°C/W
2/5		7929237	0051144	168 📟			

130

ELECTRICAL CHARACTERISTICS ($T_{amb} = 25^{\circ}C$, $V_{1} = 13.5V$ unless otherwise specified)

Parameter		Test Conditions		Min.	Тур.	Max.	Unit
Vi	Input voltage					20	V
V _o	Output voltage	V _i = 12 to 18V I _O = 5 to 150mA		8.1	8.5	8.9	V
ΔV _{I/O}	Controlled input-output dropout voltage	V _i = 5 to 10V I _o = 5 to 150mA			1.6	2.1	V
ΔV _o	Line regulation	V _i = 12 to 18V I _o = 10mA			1	20	mV
ΔV _o	Load regulation	$I_o = 5 \text{ to } 250\text{mA}$ $t_{on} = 30\mu\text{s}$ $t_{off} = \geqslant 1\text{ms}$				100	mV
ΔV _o	Load regulation	$V_i = 8.5V$ $I_O = 5 \text{ to } 150\text{mA}$ $t_{OB} = 30\mu\text{s}$ $t_{Off} = \ge 1\text{ms}$			100	250	mV
I _q	Quiescent current	I _o = 5mA			1.0	2	mA
Δlq	Quiescent current change	V _i = 6 to 18V I _o = 5 to 150mA			0.05		mA
$\frac{\Delta V_0}{\Delta T}$	Output voltage drift	I ₀ = 10mA			1.2		mV/°C
SVR	Supply voltage rejection	V _{iac} = 1V _{rms} f = 100Hz I _o = 150mA	V _{IDC} = 12 to 18V		71		dB
			V _{IDC} = 6 to 11V		35 (*)		dB
^I sc	Short circuit current			250	300		m A
ton	Switch on time	I _o = 150mA	V _i = 5 to 11V V _i = 11 to 18V		500 (*) 300	_	ms ms
T_{JSD}	Thermal shut down				150		°c

^(*) Depending of the CFT capacitor

PRINCIPLE OF OPERATION

During normal operation (input voltage upper than $V_{I\,MIN} = V_{OUT\,NOM} + \Delta V_{I/O}$). The device works as a normal voltage regulator built around the OP1 of the block diagram.

The series pass element use a PNP-NPN connection to reduce the dropout. The reference voltage of the OP1 is derived from a REF through the OP2 and Q3, acting as an active zener diode of value $V_{\rm REF}$.

In this condition the device works in the range (1) of the characteristic of the non linear drop control unit (see fig. 2)

The output voltage is fixed to its nominal value:

$$V_{OUT\ NOM} = V_{REF} (1 + \frac{R1}{R2}) = V_{CFT} (1 + \frac{R1}{R2})$$

$$\frac{R1}{R2}$$
 = INTERNALLY FIXED RATIO = 2.4

The ripple rejection is quite high (71 dB) and independent from $C_{\rm FT}$ value.

On the usual voltage regulators, when the input voltage goes below the nominal value, the regulation transistors (series element) saturate bringing the system out of regulation making it very sensible to every variation of the input voltage. On the contrary, a control loop on the L4918 consents to avoid the saturation of the series element by regulating the value of the reference voltage (pin 2). In fact, whenever the input voltage decreases below V_{1 MIN} the supervisor loop, utilizing a non linear OTA, forces the reference voltage at pin 2 to decrease by discharging C_{FT}. So, during the static mode, when the input volt-

age goes below V_{MIN} the drop out is kept fixed to about 1.6V. In this condition the device works as a low pass filter in the range (2) of the OTA characteristic. The ripple rejection is externally adjustable acting on C_{FT} as follows:

SVR (jw) =
$$\left| \frac{V_1 (jw)}{V_{out} (jw)} \right| =$$

$$\left| 1 + \frac{10^{-6}}{\frac{gm}{jwC_{FT}}} + \frac{R1}{R2} \right|$$

Where:

gm = $2 \cdot 10^{-5} \Omega^{-1} = \text{OTA'S typical transconductance value on linear region}$

$$\frac{R1}{R2}$$
 = fixed ratio

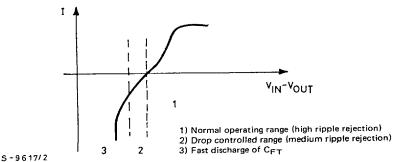
 C_{FT} = value of capacitor in μF

The reaction time of the supervisor loop is given by the tranconductance of the OTA and by $C_{\rm FT}$. When the value of the ripple voltage is so high and its negative peak is fast/enough to determine an istantaneous decrease of the dropout till 1.2V, the OTA works in a higher transconductance condition [range (3) of the characteristic] and discharge the capacitor rapidously.

If the ripple frequency is high enough the capacitor won't charge itself completely, and the output voltage reaches a small value allowing a better ripple rejection; the device's again working as a filter (fast transient range).

With $C_{FT}=10~\mu F$; f = 100 Hz a SVR of 35 is obtained.

Fig. 2 - Nonliner transfer characteristic of the drop control unit



7929237 0051146 T30 **m**

4/5 132

Fig. 3 - Supply voltage rejection vs. frequency

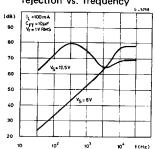


Fig. 4 - Supply voltage rejection vs. input voltage

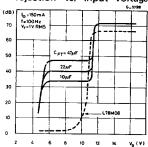
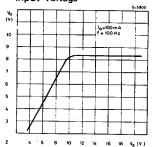


Fig. 5 - Output voltage vs input voltage



7929237 0051147 977